



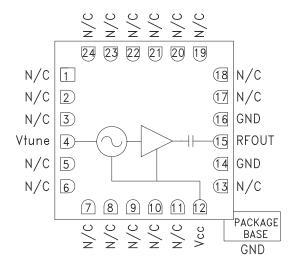
WIDEBAND MMIC VCO w/ BUFFER AMPLIFIER, 4 - 8 GHz

Typical Applications

Low Noise wideband MMIC VCO is ideal for:

- Industrial/Medical Equipment
- Test & Measurement Equipment
- Military Radar, EW & ECM

Functional Diagram



Features

Wide Tuning Bandwidth

Pout: +5 dBm

Low SSB Phase Noise: -100 dBc/Hz @100 kHz

No External Resonator Needed

Single Positive Supply: +5V @ 55 mA RoHS Compliant 4 x 4 mm SMT Package

General Description

The HMC586LC4B is a wideband GaAs InGaP Voltage Controlled Oscillator which incorporates the resonator, negative resistance device, and varactor diode. Output power and phase noise performance are excellent over temperature due to the oscillator's monolithic construction. The Vtune port accepts an analog tuning voltage from 0 to +18V. The HMC586LC4B VCO operates from a single +5V supply, consumes only 55 mA of current, and is housed in a RoHS compliant SMT package. This wideband VCO uniquely combines the attributes of ultra small size, low phase noise, low power consumption, and wide tuning range.

Electrical Specifications, $T_{\Delta} = +25^{\circ}$ C, Vcc = +5V

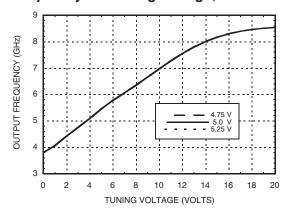
Parameter	Min.	Тур.	Max.	Units
Frequency Range		4.0 - 8.0		
Power Output	2	5		dBm
SSB Phase Noise @ 100 kHz Offset		-100		dBc/Hz
SSB Phase Noise @ 10 kHz Offset		-75		dBc/Hz
Tune Voltage (Vtune)	0		18	V
Supply Current (Icc) (Vcc = +5.0V)	40		75	mA
Tune Port Leakage Current (Vtune = +15V)			10	μΑ
Output Return Loss		7		dB
2nd Harmonic		-14		dBc
Pulling (into a 2.0:1 VSWR)		4		MHz pp
Pushing @ Vtune= +5V		40		MHz/V
Frequency Drift Rate		0.8		MHz/°C



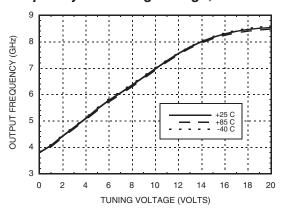


WIDEBAND MMIC VCO w/ BUFFER AMPLIFIER, 4 - 8 GHz

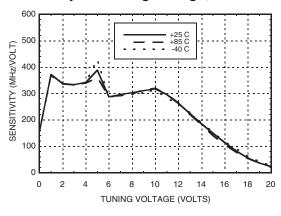
Frequency vs. Tuning Voltage, Vcc = +5V



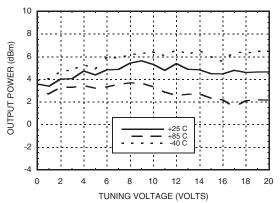
Frequency vs. Tuning Voltage, T = +25 C



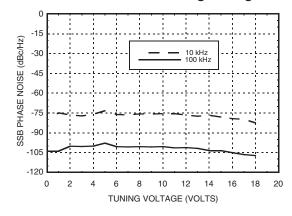
Sensitivity vs. Tuning Voltage, Vcc= +5V



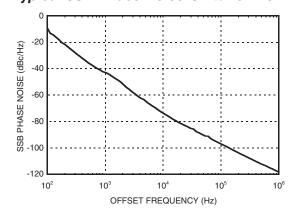
Output Power vs. Tuning Voltage, Vcc= +5V



SSB Phase Noise vs. Tuning Voltage



Typical SSB Phase Noise @ Vtune= +5V







WIDEBAND MMIC VCO w/ BUFFER AMPLIFIER, 4 - 8 GHz

Absolute Maximum Ratings

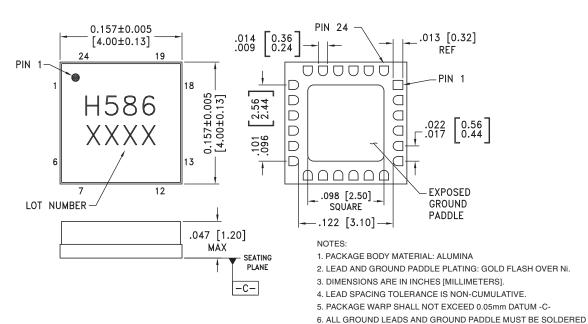
Vcc	+5.5 Vdc
Vtune	0 to +22V
Junction Temperature	135 °C
Continuous Pdiss (T = 85°C) (derate 12.5 mW/°C above 85°C)	625 mW
Thermal Resistance (junction to ground paddle)	80 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C



Outline Drawing

BOTTOM VIEW

TO PCB RF GROUND.



Pin Number	Function	Description	Interface Schematic
1 - 3, 5 - 11, 13, 17 - 24	1 N/G 1		
4	Vtune	Control Voltage and Modulation Input. Modulation bandwidth dependent on drive source impedance. See "Determining the FM Bandwidth of a Wideband Varactor Tuned VCO" application note.	Vtune ○
12	Vcc	Supply Voltage Vcc= +5V	Vcc O 20pF

Pin Descriptions



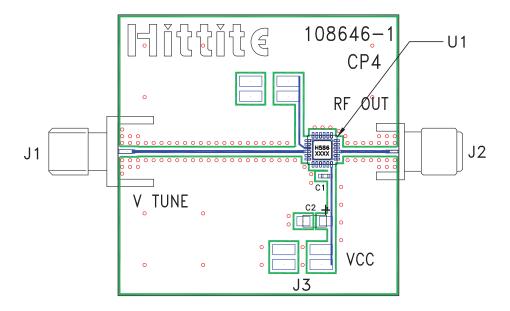


WIDEBAND MMIC VCO w/ BUFFER AMPLIFIER, 4 - 8 GHz

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
14, 16	GND	Package bottom has an exposed metal paddle that must also be RF & DC grounded.	GND =
15	RFOUT	RF output (AC coupled)	RFOUT

Evaluation PCB



List of Materials for Evaluation PCB 108648 [1]

Item	Description	
J1	PCB Mount SMA RF Connector, Johnson	
J2	PCB Mount SMA Connector, SRI	
J3	DC Header	
C1	1000 pF Capacitor, 0402 Pkg.	
C2	4.7 μF Capacitor, Tantalum	
U1	HMC586LC4B VCO	
PCB [2] 108646 Eval Board		

[1] Reference this number when ordering complete evaluation $\ensuremath{\mathsf{PCB}}$

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed ground paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.